Geometry and Conductance of AlW ires Suspended between Sem i-In nite Crystalline Electrodes

Tomoya Ono and Kikuji Hirose

G raduate School of Engineering, O saka University, Suita, O saka 565-0871, Japan

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We present a rst-principles study of a coherent relationship between the optim ized geometry and conductance of a three-alum inum -atom wire during its elongation process. Our simulation employs the most de nite model including sem i-in nite crystalline electrodes using the overbridging boundary-matching method [Phys. Rev. B 67, 195315 (2003)] extended to incorporate nonlocal pseudopotentials. The results that the conductance of the wire is $1 G_0$ and the conductance trace as a function of electrode spacing shows a convex downward curve before breaking are in agreement with experimental data.

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A tom ic-scale w ires, w hich can be produced by scanning tunneling m icroscopy and break-junction techniques, are the objects of considerable attention [1], since the properties of such minute systems with low dimensionality can be di erent from those of bulks; as the size of the structure becom es sm aller than the electronic m ean free path, the electron transport becom es ballistic and the conductance is dom inated by the electronic structure. To date, there have been a great deal of geom etrical for revealing the mechanical and electrical behavior of such m inute wires. Am ong the most exciting discoveries was that a single strand of gold atom s suspended between electrodes manifests conductance quantization in steps of $G_0 = 2e^2 = h$ [2] as electrode spacing is increased, where e is the electron charge and h is Planck's constant. Furtherm ore, other studies show ed that an atom ic-scale w ire made of alum inum atom sexhibits more complicated and even more interesting features; that is, the plateaus of conductance steps are not at but have a positive slope before the wire breaks [3, 4]. This som ewhat counterintuitive result in plies that the conductance increases even though the electrodes are pulled apart.

On the theoretical side, there are many rst-principles studies for examining electronic structure and transport properties of atom ic-scale wires using tight-binding approximation and/or the structureless jellium electrodes [5, 6, 7, 8, 9, 10, 11, 12, 13], some of which reported results consistent with experimental data. For more strict theoretical predictions on details of electron conduction properties, it would be mandatory to completely eliminate artifacts and employ a realistic model where electrodes consist of truly semi-in nite crystals. Recently, the overbridging boundary-matching (OBM) formalism [14, 15], which is a novel rst-principles treatment of electron transport properties for nanoscale junctions sandwiched between bona- de semi-in nite crystalline electrodes, has been developed.

In this Letter, we implement elaborate st-principles calculations with the incorporation of the OBM form alism to elucidate a close relationship between the relaxed geometrical structure and electronic conductance of the 3-alum inum - atom wire during the elongation process us-

ing a model in which the wire is suspended between two sem i-in nite Al(001) bulks. To the best of our know edge, this is the st theoretical investigation of this relationship where the optimized alum inum wire is connected to genuine sem i-in nite alum inum crystalline electrodes which are gradually separated. We nd that this 3-alum inum -atom wire has a conductance of $1 G_0$, and there is only one channel that gives a dom inant contribution to the electron conduction at the Ferm i level. The conductance trace as a function of electrode spacing decreases in the early stage of the elongation process and shows a m in im um; in the case of shorter electrode spacing, a loop current (LC) is induced around the center atom of the bent wire so as to boost electron transm ission. With an increase in electrode spacing, the LC weakens and the conductance reduces. W hen electrode spacing is still further increased, the wire form s into a straight structure with a one-dimensional character, which contributes to the enhancem ent of electron transm ission. A s a result, the curve of the conductance trace is convex dow nw ard before the wire breaks, and subsequently the conduction channels between the two electrodes disappear.

First, we determ ine the optim ized atom ic structure of the 3-alum inum - atom wire suspended between the Al(001) electrodes during its elongation. Our rstprinciples simulations are based on the real-space nitedi erence method [16], which enables us to determ ine both the self-consistent electronic ground state and the optim ized geometry with a high degree of accuracy by virtue of the tim esaving double-grid technique [17] and the direct m in imization of the energy functional [18]. The norm-conserving pseudopotentials [19] of Troullier and Martins [20] are used to describe the electron-ion interaction. Exchange-correlation e ects are treated by the local-density approximation [21] in the density-functional theory. The nine-point nite-di erence case, i.e., the case of $N_f = 4$ in Eq. (A2) (here and hereafter, the equation num ber refers to that in Ref. [15]), is adopted for the derivative arising from the kinetic-energy operator in the Kohn-Sham equation. We set a cuto energy of 25 Ry, which corresponds to a grid spacing of 0.63 a.u., and furFIG.1: Schem atic representation of the model. The rectangle enclosed with broken lines represents the supercell used to evaluate the optimized atom ic con guration and electronic structure.

ther take a higher cuto energy of 224 R y in the vicinity of the nuclei with the augmentation of double-grid points [17].

For optim ization, a conventional supercell, which is indicated by the rectangle enclosed with broken lines in Fig. 1, is employed. The size of the supercell is chosen $asL_x = L_y = 15.12 a.u.$ and $L_z = 22.68 a.u. + 2d.$ Here, the z axis is taken along the wire axis, the x and y axes are perpendicular to the wire, L_x , L_y and L_z are the lengths of the supercell in the x, y and z directions, respectively, and d is the average value for the projections of interatom ic distances between adjacent atom softhe wire onto the z component. The wire is connected to the square bases with the side length of $\frac{d_0}{d_2}$ at both its ends, modeled after the [001] alum inum strands, and all of these components intervene between the electrodes produced from three atom ic layers of the A 1(001) surface. The distance between the electrode surface and the basis as well. as that between the basis and the edge atom of the wire is chosen to be $0.5a_0$, where $a_0 (= 7.56 a.u.)$ is the lattice constant of the alum inum crystal. The position of the centralatom of the wire is optim ized on the (110) plane while the other atom s are xed during the rst-principles structural optim ization. We nd that the wire exhibits a bent structure below electrode spacing Les of 26.46 a.u. W hen elongated up to $L_{es} = 27.09 a.u.$, the wire manifests geom etrical transition from a bent wire to a straight one, and nally distorts at $L_{es} = 28.35 \text{ a.u.}$ [23]

We next explore the electron transmission of the wire at zero-bias limit with the Landauer formula $G = tr(T \ ^{y}T)G_{0}$, where T is a transmission matrix. The global wavefunctions for in nitely extended states continuing from one electrode side to the other are evaluated by the OBM method [15]. For the determination of the electronic structure of the transition region which is composed of wire, bases, and a couple of atom ic layers of electrodes (see Fig. 1) as well as the electronic structure of the alum inum crystalline electrode is calculated self-consistently employing a standard supercell geometry with a three-dimensional periodic boundary. The wavefunctions in the crystalline electrode region are composed of when the crystalline electrode region are composed.

FIG. 2: Channel transm issions at the Ferm i level for the three-alum inum -atom wires as a function of electrode spacing.

puted by the generalized eigenvalue equation of Eq. (19), and in order to circum vent a num erical instability caused by evanescent waves, the wavefunction-m atching form ula Eq. (11) at the interfaces between the electrode and transition regions is described in terms of the ratio m atrices R's, which are de ned by Eqs. (25) and (B9). Furthermore, for calculating the conduction properties of the alum inum wires with s- and p-valence orbitals, we here extend the OBM scheme to the case including the nonbcalparts of the pseudopotentials of T roullier and M artins [20]; since the nonlocal parts are represented by block m atrices in the K ohn-Sham H am iltonian when the realspace nite-di erence m ethod is applied, the nine-point

nite-di erence form ula for the kinetic-energy operator is adopted so that the o -diagonal elem ents of the nitedi erence form ula can entirely cover the block matrices of the nonlocal parts. Consequently, the Ham iltonian is described by a block-tridiagonal matrix com posed of $4N_{xy}$ -dimensional block matrices, where N_{xy} is the num ber of grid points on the x-y grid plane [24].

Figure 2 shows the channel transm issions at the Ferm i level as a function of L_{es} . The eigenchannels are investigated by diagonalizing the Herm itian matrix T $^{\rm Y}T$ [7]. There are certain features that are common to the undistorted 3-alum inum atom wire: throughout all the ranges of electrode spacing below $L_{es}=28.35~{\rm a.u.}$, the rst channel, which has the characters of s and p_z for a straight wire, is widely open, while the second and third ones, which have the characters of p_x and p_y and are degenerate for the straight wire, have sm all transm ission 1.0 10^{-3} , and the resultant electronic conductance is

1 G₀. Moreover, one can see that the conductance trace as a function of electrode spacing exhibits a convex downward curve having a minimum at $L_{es}=26.46$ a.u. Our result regarding the conductance trace accords with the available experimental data [3, 4], and in particular, is in excellent agreement with the data recently reported by M izobata et al. [4].

To gain an insight into this unique conductance trace, we plot in Fig. 3 the electron-density distributions and current densities of the rst channel at the Ferm i level for

several electrode spacings. The states incident from the left electrode are depicted. In the case of a short electrode spacing such as $L_{es} = 24.57 \text{ a.u.}$, the channel transm ission is 1, and the rst channel current form s an LC rotating around the center atom . U pon elongating electrode spacing, one nds that the LC weakens and consequently, the transmission exhibits a minimum. The electron transport through the wire is closely associated with the behavior of the LC : in fact, as the center atom is displaced upward from the most stable position depicted in Fig. 3, the LC becomes enhanced to increase the transm ission. W hen the wire is stretched up to electrode spacing of 27.09 a.u., where it form s into a straight wire from a bent wire, the transmission recovers 0.9. At this stage, the LC completely disappears and the current is axially symmetric around the wire axis. In the straight wire, the one-dim ensional character strengthens, therefore the

rst channeltransm ission at the Ferm i level is larger than that of the bent wire of $L_{es} = 25.83 \text{ a.u.}$ A fier the wire's distortion, there are no conduction channels between the two electrodes.

O ne of the previous theoretical studies on the conductance of the 3-alum inum -atom wire employing structureless jellium electrodes observed a similar current density [7]. However, this simulation does not have su cient accuracy to discuss strictly quantitative properties of electron transport because it was implemented using an inferior pseudopotential made only of local parts and a very restricted model where the bond lengths of the wire are

xed to be 5.4 a.u. For a de nite interpretation of the relationship between geometry and conductance of the wire, a highly transferable pseudopotential having nonlocal parts and structural optimization are indispensable. Our result that the conductance is $1 G_0$ is in accordance with that of the ab initio tight-binding calculation incorporating the square bases made of alum inum atoms [13]. Com pared with the other studies using nonlocal pseudopotentials and structureless jellium electrodes without any atom ic layers or bases, most of the channel transmissions and conductance in the present study are smaller than those of the other studies: Lang [5] and K obayashi et al. [8] reported that the conductance of the wire is 1.5 G_0 , and moreover, K obayashi et al. reported the transmissions of the second and third channels are 0.3. In these calculations adopting jellium electrodes without any atom ic layers, the channel transmissions and electronic conductance sensitively depend on direct e ects from the jellium electrodes, and therefore the di erence between our results and theirs may be mainly attributed to the absence of atom ic layers or bases.

In summary, we have studied a close relationship between the optimized geometry and electronic conductance of the 3-alum inum -atom wire suspended between genuine sem i-in nite alum inum crystalline electrodes. ndings are that (1) the 3-alum inum -atom wire Our sandwiched between two Al(001) electrodes exhibits an electronic conductance of $1 G_0$, (2) there is one conduction channel which widely opens at the Ferm i level, and (3) the conductance trace as a function of electrode spacing behaves so as to draw a convex dow nw ard curve before the wire breaks. In the bent wire with a short electrode spacing of L_{es} 26.46 a.u., the electron transport property of the wire depends on the strength of the LC. On the other hand, in the case of a long electrode spacing of L_{es} 27.09 a.u., the one-dimensional character of the straight wire contributes tow ards the electron conduction to give rise to a conductance of $1 G_0$. This result of the conductance trace is in accordance with experim ental data. W ork in progress is the study on the electron conduction of the alum inum wire attached to the electrodes having other crystal faces such as the (111) and (110) planes.

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4

FIG. 3: (Color). Channel electron and current density distributions at the Ferm i level for the three-alum inum -wire at (A) $L_{es} = 24.57 \text{ a.u.}$, (B) $L_{es} = 25.83 \text{ a.u.}$, (C) $L_{es} = 27.09 \text{ a.u.}$, and (D) $L_{es} = 28.35 \text{ a.u.}$. The upper panels show contours of the channel electron distributions, and the lower panels show arrows denoting the channel current distributions on the (110) plane. The states incident from the left electrode are shown. The large and sm all spheres indicate the atom ic positions on and below the cross section, respectively.

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+ 2d, and found no qualitative di erences. This implies that the supercell lengths of 15.12 a.u. in the x and y directions taken in the text are adequate to ensure non-interaction of the wires in neighboring cells.

[24] In the present case of the alum inum wire, we choose the core radius of the nonlocal pseudopotentials to be 2.5 a.u., so that the core region contains 8 x-y grid planes, and the matrix B_z de ned in Ref. [15], which corresponds to an o diagonal block matrix in a block-tridiagonal form, becomes $4N_{xy}$ dimensional.

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